NSN 5961-00-417-7845

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-417-7845 **Inclosure Material:** Metal **Overall Length:** 2.250 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-9 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** 1.443 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 175.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Test Data Document:** 49956-146425 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 insulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No ---

Fiig:

A110a0